

KSE44H Series

General Purpose Power Switching Applications

- Low Collector-Emitter Saturation Voltage : V_{CE}(sat) = 1V (Max.) @ 8A
- Fast Switching Speeds
- Complement to KSE45H



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter		Value	Units
V _{CEO}	Collector-Emitter Voltage : KSE4	4H 1,2	30	V
	: KSE4	4H 4,5	45	V
	: KSE4	4H 7,8	60	V
	: KSE4	4H 10,11	80	V
V _{EBO}	Emitter- Base Voltage		5	V
I _C	Collector Current (DC)		10	Α
I _{CP}	*Collector Current (Pulse)		20	Α
P _C	Collector Dissipation (T _C =25°C)		50	W
P _C	Collector Dissipation (T _a =25°C)		1.67	W
TJ	Junction Temperature		150	°C
T _{STG}	Storage Temperature		- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CES}	Collector Cut-off Current	V_{CE} = Rated V_{CEO} , V_{EB} = 0			10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			100	μΑ
h _{FE}	*DC Current Gain : KSE44H 1,4,7,10 : KSE44H 2,5,8,11	V _{CE} = 1V, I _C = 2A	35 60			
V _{CE} (sat)	*Collector-Emitter Saturation Voltage : KSE44H 1, 4, 7 10 : KSE44H 2, 5, 8,11	$I_C = 8A, I_B = 0.8A$ $I_C = 8A, I_B = 0.4A$			1	V
V _{BE} (sat)	*Base-Emitter Saturation Voltage	$I_C = 8A, I_B = 0.8A$			1.5	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$		50		MHz
f _T C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		130		pF
t _{ON}	Turn ON Time	$V_{CC} = 20V, I_{C} = 5A$		300		ns
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 0.5A$		500		ns
t _F	Fall Time			140		ns

^{*} Pulse test: PW≤300μs, Duty cycle≤2%

Typical Characteristics

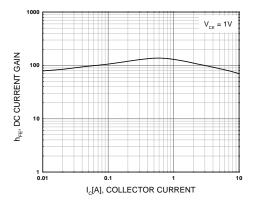


Figure 1. DC current Gain

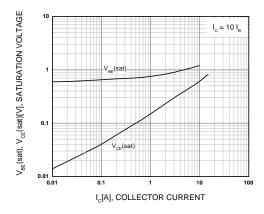


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

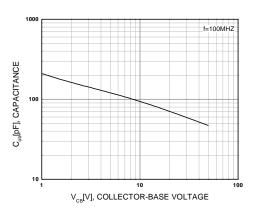


Figure 3. Collector Output Capacitance

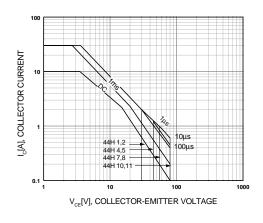


Figure 4. Safe Operating Area

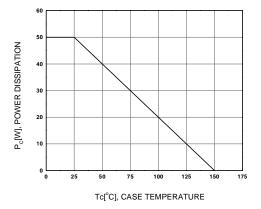
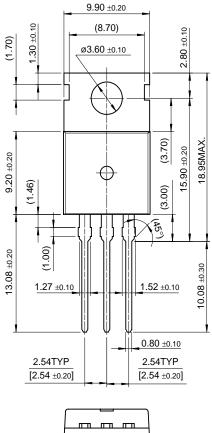


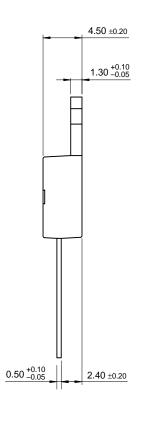
Figure 5. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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